Disentangling electron- and electric-field-induced ring-closing reactions in a diarylethene derivative on Ag(1 1 1)

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Abstract

Using scanning tunneling microscopy and spectroscopy we investigate the adsorption properties and ring-closing reaction of a diarylethene derivative (C₅F₄Py) on a Ag(1 1 1) surface. We identify an electron-induced reaction mechanism, with a quantum yield varying from 10⁻¹⁴–10⁻⁹ per electron upon variation of the bias voltage from 1–2V. We ascribe the drastic increase in switching efficiency to a resonant enhancement upon tunneling through molecular orbitals. Additionally, we resolve the ring-closing reaction even in the absence of a current passing through the molecule. In this case the electric-field can modify the reaction barrier, leading to a finite switching probability at 4.8K. A detailed analysis of the switching events shows that a simple plate-capacitor model for the tip-surface junction is insufficient to explain the distance dependence of the switching voltage. Instead, describing the tip as a sphere is in agreement with the findings. We resolve small differences in the adsorption configuration of the closed isomer, when comparing the electron- and field-induced switching product.

Keywords: molecular switch, scanning tunneling microscopy, molecular electronic

1. Introduction

Diarylethene (DAE) molecules are prototypes of molecular ring-opening/closing switches [1–3]. In the ring-closed form the molecules are fully-π-conjugated, whereas the conjugation is interrupted in the open form. Therefore, the two isomers exhibit drastic differences in their optical and conductance properties, while their geometries are only slightly changed. The optical absorption spectrum moves from the ultra-violet range in the open form to the visible range in the closed isomer [3, 4]. The conductance ratio, which is an important figure of merit as the ON/OFF ratio, is in the order of 10 to 300 depending on the endgroups [5–9]. The intriguing combination of structural, optical and electronic properties renders these molecules highly-promising candidates for their application in electronic and opto-electronic devices [10–12].

Device applications also require reliable means to switch between the two states. Incorporation of the molecules into device geometries, however, crucially modifies the properties of the individual isomers and often deteriorates the switching ability [13, 14]. Fascinating results of reversible light-induced switching at room temperatures have recently been achieved in DAEs contacted to graphene electrodes [8].

Despite of the huge progress made in light-triggered switching, it is still necessary to consider other stimuli. This is especially important for applications in single-molecule devices because of the fundamental limits of light focusing. In contrast, charge flow through molecules can be limited to the individually addressable molecule. In fact, electron-induced switching is widely investigated for switching molecules on metal electrodes [13, 15–22]. Voltage biasing the molecules to control the current inevitably includes the...
presence of an electric field. The electric field by itself may affect the potential energy landscape of the molecular isomers and thus modify or induce/hinder a switching process [23, 24]. It is therefore important to understand both, the electric field as well as the electron-induced switching processes, and the interplay of these effects.

To elucidate the electron and electric-field effects on a ring-closing reaction, we investigated 1,2-bis(2-methyl-5-((Z)-(2-cyano-2-(pyridin-4-yl)vinyl))furanyl-3-yl) hexafluorocyclopentene (CSF-4Py) [25] (figure 1(a)) on a Ag(1 1 1) surface with low temperature scanning tunneling microscopy (STM) and scanning tunneling spectroscopy (STS). This DAE-derivative is functionalized with oxygen containing furanyl and therefore expected to interact less with a metal than the more common parent compound, which contains sulfur bearing thiophenyl aryl-rings [6, 9]. Adsorbed on Ag(1 1 1), the molecules self-assemble in islands. We show that the open form can be switched into the closed form by the STM tip. We identify an electron-induced as well as an electric-field-induced reaction. These processes can be disentangled by current- and height-dependent determination of the switching efficiency. The quantum yield for electron-induced switching is resonantly enhanced when tunneling through the LUMO derived orbitals. Our detailed analysis further reveals that the typically assumed plate-capacitor model is insufficient to describe the distance dependence of the switching voltage. We show that the next higher approximation of a spherical tip is a better model to describe the behavior.

2. Experimental details

The CSF-4Py diarylethene was synthesized according to [6]. The Ag(1 1 1) sample was cleaned by repeated Ne⁺ sputtering and annealing cycles. The open CSF-4Py isomers were evaporated from a Knudsen cell at 440 K onto the Ag(1 1 1) surface held at room temperature in ultrahigh vacuum. The tungsten STM tip was covered with silver by indentation into the clean surface. The quality of the tip was checked on the clean surface by observing the silver surface state in spectroscopy. All STM measurements were performed with a home-built STM at a temperature of 4.8 K. Differential conductance spectra were recorded with an open feedback-loop using lock-in detection with a modulation frequency of 910 Hz and a root mean square modulation amplitude of 15 mV.

3. Results and discussion

3.1. Molecular adsorption structure

Evaporation of the open isomer of CSF-4Py from the powder onto a clean Ag(1 1 1) surface at room temperature leads to densely-packed molecular islands of a monolayer height (figure 1(b)). High resolution STM images as in figure 1(c) allow for an assignment of the individual molecules. Similar to their appearance on Au(1 1 1) [9], each molecule is roughly of triangular shape with a brighter feature corresponding to the switching unit of the DAE, and two lower parts associated to the cyano-vinyl-pyridine groups of the molecule. We find four orientations of the molecules rotated by 90° with respect to each other.

An important observation is that with our evaporation conditions, all molecules appear similar in shape indicating that they are all in the same isomeric state. However, a modification of the appearance of the molecule can be induced deliberately by the STM tip as revealed by a comparison of the topographies in figures 2(a) and (b), where one molecule appears brighter in the second image. This kind of change is obtained by applying a voltage ramp over the molecule until the simultaneously recorded current drops drastically (inset in figure 2(c)).

The differential conductance spectra (dI/dV) of the molecule before (black) and after (red) the modification are shown in figure 2(c). The initial molecule exhibits two resonances at positive bias (∼1.2 V and ∼2 V) and none at negative bias in the range down to −2 V. The spectrum of the bright molecule is drastically different with one resonance at positive bias (∼1.3 V) and one at negative (−1.2 V). The latter resonance dominates the STM topography in figure 2(b) and allows for the reliable and fast identification of the isomeric state, which will be important for the following experiments. Similar changes in the electronic structure were also observed for CSF-4Py molecules on Au(1 1 1) and associated to the switching from the open to the closed isomer [9]. The reduction of the HOMO-LUMO gap is in agreement with the change from a non-conjugated (open form) to a fully conjugated molecule (closed form). The presence of two unoccupied states with similar energies in the initial molecule can be explained by the lifting of the degeneracy of the LUMO state of the open isomer [9]. The switching described above was reproducible on hundreds of molecules. However, we could not observe a back-switching from the closed to the open form.

3.2. Electron-induced switching

Next, we aim at resolving the switching mechanism. We first determine the rate of the switching as a function of tunneling current. Because the switching is non-reversible, the rate is determined as shown exemplary in figure 3(a). While the current is kept constant, the dI/dV signal and the tip height on the addressed molecule are monitored. A switching event is indicated by a sudden change of the dI/dV signal and the tip height. To confirm the ring-closing reaction, we recorded dI/dV spectra afterward. Only when the typical resonance structure of the closed isomer is observed, we take this event into account for the statistical analysis. The rate is then calculated from the time laps between parking the STM tip over the specific molecule and having set the specific bias voltage and the sudden change in tip-height and dI/dV signal. We carry out this process for more than 200 molecules at different currents and different bias voltages.

In figure 3(b) we plot the rate as a function of tunneling current for a voltage of 2 V. The current dependence of the switching rate follows a law in I⁷, with N = 0.74 ± 0.04. A power N = 1 would suggest a one-electron process, N = 2 a
two-electron process, etc [16, 21, 26–28]. An exponent less than one thus hints at a one-electron process mixed with an electron-independent process. This will be discussed in more detail in section 3.3. By converting the rate at a specific current into the electron yield for the switching, we obtain the plot in figure 3(c) for a bias voltage of 2 V. The horizontal line labels a constant yield with current. We notice a small tendency of a decrease of yield with tunneling current, albeit a constant line lies almost within the error bars. We will discuss the origin of a possible deviation below.

We further evaluate the switching yield as a function of bias voltage in figure 3(d). Below 1 V, the yield is negligibly small. It increases to $2 \times 10^{-13}$ per electron at 1.2 V. A further rapid increase in the yield is observed at $\sim$1.8 V and seems to level off again with a yield of $1 \times 10^{-9}$ per electron at 2.2 V. The energy-dependence of this drastic increase by four orders of magnitude qualitatively follows the energy alignment of the molecular resonances as detected in $dI/dV$ spectra for the open isomer (red curve). Indeed, the threshold at $\sim$1 V corresponds to the first resonance and the more pronounced increase at $\sim$1.8 V is observed at the energy close to the second resonance. This behavior shows that the switching process is resonantly enhanced by electrons tunneling into the unoccupied molecular orbitals [19–21, 29]. We note also that in the negative bias regime, where we did not detect any molecular states of the open isomer, we also observe no switching.

While these observations highlight the importance of tunneling through the LUMO derived resonances, we cannot ascertain that the switching actually occurs in the excited state. It is also possible that the switching proceeds after the fast relaxation of the excited state, being triggered by the transient dynamics [24].

3.3. Electric-field-induced switching

The observations in the previous section suggest an electron-induced process. However, the deviation of the switching rate from a strict proportionality with the current ($N < 1$) and the non-constant yield with current indicate that another parameter affects the switching process.

To determine this additional effect, we aim at separating it from the current-induced switching. For this, we carry out experiments by retracting the tip from the surface. In figure 4(a), the tip was withdrawn by 9 nm from the usual tunneling conditions, and a 9 V-voltage pulse was applied during 60 s at the position marked by the white cross in the first topography. At this far distance, one can safely neglect the effect of any tunneling current. Nonetheless, some molecules are modified after the voltage pulse (figure 4(b)). Note that these modifications are not only localized directly underneath the tip position during the pulse, but can appear in a radius of up to 5 nm. Subsequent $dI/dV$ spectra recorded on these molecules prove them to be switched into the closed isomer of the CSF–4Py.

A non-local switching in the absence of tunneling current can be associated with the electric field present in the junction

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**Figure 1.** (a) Chemical structure of the open (left) and closed (right) forms of the CSF–4Py molecule. (b) Large-scale STM image (75 × 75 nm$^2$) of the Ag(1 1 1) surface with molecular islands of CSF–4Py ($V = 0.8$ V, $I = 32$ pA). (c) High resolution STM image (8 × 8 nm$^2$) of a molecular island ($V = 0.5$ V, $I = 120$ pA). The model of the CSF–4Py molecule calculated in gas phase is overlaid to indicate the proposed assembly structure.
[23]. To confirm that, we determine the minimum voltage necessary to observe the switching as a function of the tip-sample distance, for a bias pulse of 60 s (black dots in figure 4(c)). Usually, a simple plate-capacitor model is used to determine the electric field in the STM junction with \( E = V / \Delta z \). This would yield a linear dependence of the threshold voltage with the tip sample distance, which is clearly not the case here. One may argue that a finite tunneling current may be responsible for the switching at small retraction distances. We therefore distinguish two regimes. The gray dashed line in figure 4(c) at 20 Å tip retraction separates the regimes of finite current and negligible current, i.e. a current below the fA range. If one extrapolates the threshold voltage by a linear dependence, the line does not cross zero voltage at tip-molecule contact. Hence, the plate-capacitor model is insufficient to explain the distance-dependence of the switching voltage.

A better model of the tip-sample junction may be a description by a spherical tip in front of a plate. The electric field in this geometry is not easy to calculate, but the \( z \) component of the electrostatic field in the vicinity of the sphere may be approximated by [30, 31]:

\[
E = \frac{V}{\Delta z \log(\sqrt{D^2 + \Delta z^2} + \sqrt{1 + D})},
\]

with \( D = \Delta z/R \), where \( R \) is the radius of the tip, \( V \) the bias voltage and \( \Delta z \) is the tip-sample distance. From this formula we can therefore determine the required bias voltage to keep the electric field constant at a specific tip-sample distance.

Note that we observed the switched isomers typically within a radius of 5 nm away of the position of the pulse \( \Delta x \) in the scheme of figure 4(c). This has to be considered in our model replacing in equation (1) \( \Delta z \) by \( \sqrt{(R + \Delta z)^2 + \Delta x^2} - R \).

Using this model, we fit our data for \( \Delta z \) above 20 Å and obtain the curve in light blue in figure 4(c) with \( \Delta x \) being fixed at 5 nm, while \( E \) and \( R \) were fitting parameters with final values of 0.21 V Å\(^{-1} \) and 4 Å, respectively. Finally the dark blue line is obtained with the same \( E \) and \( R \) values but with \( \Delta x = 0 \). All our data points fall into the range between the two curves. Hence, a switching mechanism involving the electric field is consistent with our observations, particularly for the events with a large tip-sample distance. For the case below 20 Å, we see that the experimental points are closer to the fitting curve with \( \Delta x = 0 \). This is in agreement with our observation that switching events with small \( \Delta z \) are generally localized underneath the tip (see section 3.2). However, we also note that this regime also includes electron-induced switching events.

Importantly, we conclude that we can find switching events even in the absence of a tunneling current at large bias voltages. The presence of an electric field modifies the energy of the open and closed isomer and the barrier height between these states due to the permanent and the induced dipole within the molecule [32]. If the barrier becomes small, thermal excitations and tunneling may become sufficiently strong to effectively switch the molecule, even without any additional electron. Although one may expect a switching event in the electric field of either direction [23], we did not observe any switching at negative bias polarity. This asymmetric behavior with bias voltage is probably a result of a difference between the permanent dipole of the open and closed isomer [32].

Taking up our observation that the rate scaled as \( N^N \) with \( N = 0.74 \pm 0.04 \), we can now also understand this sublinear behavior. An increase in tunneling current is accompanied by a smaller tip-molecule distance (at the same bias voltage). Hence, the electric field raises and the deformation of the potential energy landscape leads to a lowering of the switching barrier. This increases the probability of switching without electron attachment. This explains that in average less than one electron is needed for triggering a switching process. This argument is directly connected and in line with a small decrease of the switching yield with increasing current.

### 3.4. Switching products

In the previous sections, we discussed two different mechanisms, one with electrons and one with electric field, as a trigger for the ring-closing reaction in C5-4Py. Figures 5(a) and (b) show two STM topographies with a molecule switched by electrons and in the electric field, respectively. In each image the corresponding molecule is framed by an ellipse. Figure 5(c) presents the \( \text{dI/dV} \) spectra corresponding to these two molecules. The molecule switched with an electron (with 2 V and 200 pA), exhibits a spectrum (red curve) similar to the one shown in figure 2(c). The HOMO is found at -1.2 V and the LUMO at 1.2 V. The gap thus amounts to 2.4 V. For the molecule switched in the electric field with a
pulse of 9.5 V and Δz = 8 nm, the spectrum (blue curve) is distinctly different. The HOMO-LUMO gap is essentially the same (2.2 V) but the complete spectrum is shifted to larger positive bias voltages by ~0.6 V. Moreover, the width of the resonances are narrower (300 mV compared to 600 mV) and the HOMO resonance is followed by a region of negative differential conductance. A narrower lineshape reflects a smaller degree of broadening of the electronic states arising from hybridization with the substrate. Sharp resonances in a tunneling barrier are often accompanied by signatures of negative differential conductance due to the rapid change in the transmission function [33, 34]. Hence, the closed isomer, which has been produced by the electric field, clearly exhibits a smaller electronic coupling with the substrate than the one produced by electron attachment. Additionally, the STM
topographies in figures 5(a) and (b) (recorded at 0.2 V, i.e. in the HOMO-LUMO gap to eliminate all electronic effects) reveal different apparent heights of the molecules. While the electron-switched molecule is lower than the neighboring open molecules (height profile A in figure 5(d)), the electric-field switched molecule is higher (height profile B). This observation supports our previous conclusion that the closed isomer produced by the electric field is more decoupled from the substrate. One may speculate that the electric field lifts the molecule due to the presence of a dipole.

4. Conclusions

In summary, we have investigated the switching behavior of CSF-4Py adsorbed on a Ag(1 1 1) surface by an STM tip. We could induce switching from the open to the closed form throughout a wide range of current and voltage parameters. We could identify an electron-induced and an electric-field-induced ring-closing reaction. The electron-induced switching yield is strongly enhanced by tunneling through unoccupied molecular orbitals. Below-resonance tunneling leads to a yield in the order of $10^5$ per electron, while on-resonance tunneling pushes the yield up to $10^3$ per electron. However, even in the absence of electron tunneling, switching can be observed. In this regime, the electric field modifies the barrier and leads to the ring-closing reaction. Our data also shows the limits of the commonly employed plate-capacitor model. The switching voltage can be reproduced by a model considering a spherical tip. While the analysis of switching rate, yield and distance dependence allowed us to draw a conclusive picture on the processes at work, we also noticed a difference in the adsorption state of the closed isomer depending on how the reaction proceeded. The molecules produced by the electric-field effect interact less with the substrate, presumably because they are slightly lifted from the surface. Our results highlight the interplay of electron- and field-induced switching, which is important in electronic devices.

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